

#### FACT SHEET | EM3028-C7

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## Extreme Low Power RTC Module

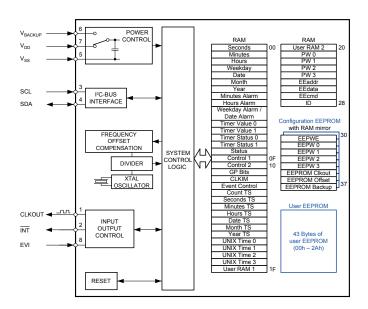
#### **General Description**

The EM3028-C7 is a SMT Real-Time Clock Module that incorporates an integrated CMOS circuit together with an XTAL. It operates under vacuum in a hermetically sealed ceramic package with metal lid.

#### **Applications**

- I loT
- I Wearable systems
- I Multi-Solar cell platforms
- I Beacons and wireless sensor networks
- I Industrial and environmental monitoring
- I Battery operated platforms

#### **Block Diagram**



#### **Features**

- I Extreme low power consumption: 40 nA @ 3 V.
- Wide operating voltage range: 1.2 V to 5.5 V.
- I Built-in tuning Fork crystal at 32'768 Hz
- 1 Time accuracy: Factory calibrated to ±1 ppm @ 25°C
- I Non-volatile configuration settings with user programmable offset value.
- I Configuration stored in EEPROM and mirrored in RAM
- I Backup Switch and Trickle Charger function.
- I Provides year, month, date, weekday, hours, minutes and seconds.
- I Automatic leap year correction; 2000 to 2099.
- I 32 bit UNIX time counter.
- I Timer, alarm and external event functions with time stamp.
- I Clock output: 32.768 kHz, 8192 Hz, 1024 Hz, 64 Hz, 32 Hz, 1 Hz.
- I 43 bytes non-volatile user memory, 2 bytes user RAM.
- I I<sup>2</sup>C-bus interface: 400 kHz.
- I Packages (RoHS compliant and Lead-free)
- I Ultra small SMD C7 package, 3.2 x 1.5 x 0.8mm Part number EM3028C7
- I TSSOP14 (with external crystal), Part number EM3028VxTP14 (x = Version nbr)

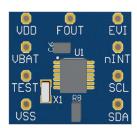
#### EM3028-C7

Module, integrated crystal

# CLKOUT EVI NINT U1 C1 VDD SCL VBACKUP SDA VSS

#### EM3028VxTP14

TSSOP14 with external Crystal





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#### Electrical Characteristics at 25°C

	Symbol	Condition	Min	Тур	Max	Unit
Supply voltage	V <sub>DD</sub>	I <sup>2</sup> C-bus active	1.2		5.5	V
Supply voltage	V <sub>DD</sub>	Time keeping	1.1		5.5	V
Current consumption Time keeping mode	I <sub>DDO</sub>	$V_{DD} = 3V$		40	60	nA
CLKOUT frequency	F <sub>CLKOUT</sub>	Programmable		32768to1		Hz
Time accuracy	∆t/t	t @ 25°C ± 1			ppm	
Aging first year max.	ΔF/F	@ 25°C		± 3		ppm

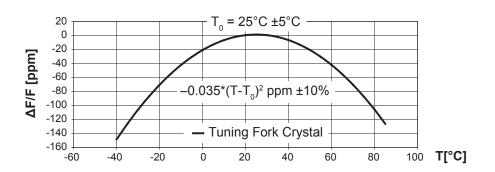
#### **Environmental Characteristics**

		Conditions	Max. Dev.
Storage temp. range		−55 to +125°C	
TA Operating temperature range		−40 to +85°C	
Shock resistance	ΔF/F	5000 g, 0.3 ms, ½ sine	± 5 ppm
Vibration resistance	ΔF/F	20 g / 10–2000 Hz	± 5 ppm

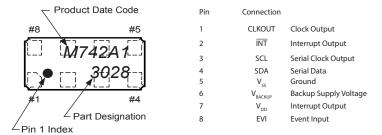
### Package, Terminations and Processing

Package-Type	Termination	Processing		
SON8	Au flashed pads	IPC/JEDEC J-STD-020C 260°C / 20-40s		

## Frequency Temperature Characteristics



#### Pin Connections Top View



#### **Ordering Information**

The versions below are considered standards and should be readily available. For the other delivery form, please contact EM Microelectronic-Marin SA. Please make sure to give the complete part number when ordering.

Part Number		Temperature	Package	Delivery Form
EM3028C7B+	RTC module with integrated 32'768 Hz Crystal Factory calibrated to +/- 1%	-40°C to +85°C	SMD C7 3.2 x 1.5 x 0.8mm	EIA Real, 1000 IC/real
EM3028VxTP14B+ Needs external 32 kHz crystal Please check with EM for available IC versions		-40°C to +85°C	TSSOP14	EIA Real, 2500 IC/real